

L-56BID

HIGH EFFICIENCY RED

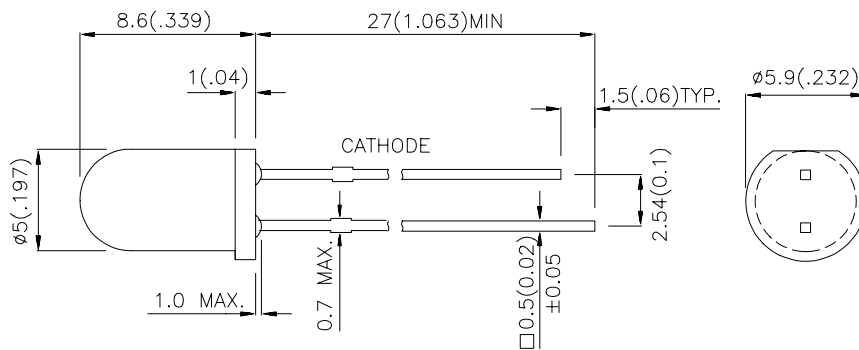
Features

- T-1 3/4 PACKAGE .
- WITH BUILT-IN BLINKING IC.
- OPERATION VOLTAGE FROM 3.5V TO 14V.
- BLINKING FREQUENCY FROM 3.0Hz TO 1.5Hz.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) V=9V		Viewing Angle
			Min.	Typ.	2θ1/2
L-56BID	HIGH EFFICIENCY RED(GaAsP/GaP)	RED DIFFUSED	18	40	60°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value..

Electrical / Optical Characteristics at T_A=25°C

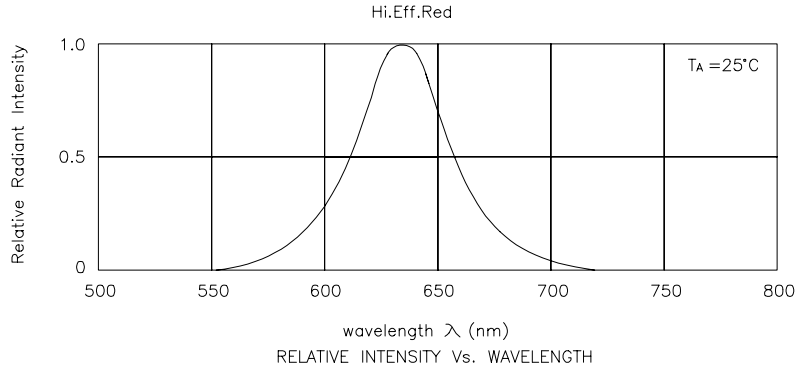
Symbol	Parameter	Device	Min	Typ	Units	Test Conditions
λ _{peak}	Peak Wavelength	High Efficiency Red		627	nm	
λ _D	Dominate Wavelength	High Efficiency Red		625	nm	
Δλ _{1/2}	Spectral Line Half-width	High Efficiency Red		45	nm	
I _F	Forward Current	High Efficiency Red	8	22	mA	Min :V _F =3.5V Typ :V _F =5V
I _{SON}	Supply Current	High Efficiency Red		8	mA	V _F =3.5V
I _{SON}	Supply Current	High Efficiency Red		44	mA	V _F =14V
f	Blink Frequency	High Efficiency Red		3	Hz	V _F =3.5V
f	Blink Frequency	High Efficiency Red		1.5	Hz	V _F =14V

Absolute Maximum Ratings at T_A=25°C

Parameter	High Efficiency Red	Units
Power dissipation	310	mW
Forward Voltage	14	V
Reverse Voltage	0.5	V
Operating Temperature	-40°C To +70°C	
Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [1]	260°C For 5 Seconds	

Note:

1. 2mm below package base.



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